Electronic Supplementary Material (ESI) for Nanoscale Advances.

Supplementary Information

Fine Pd single microwire H_2 sensor fabricated by femtosecond laser for low detection limit at room temperature

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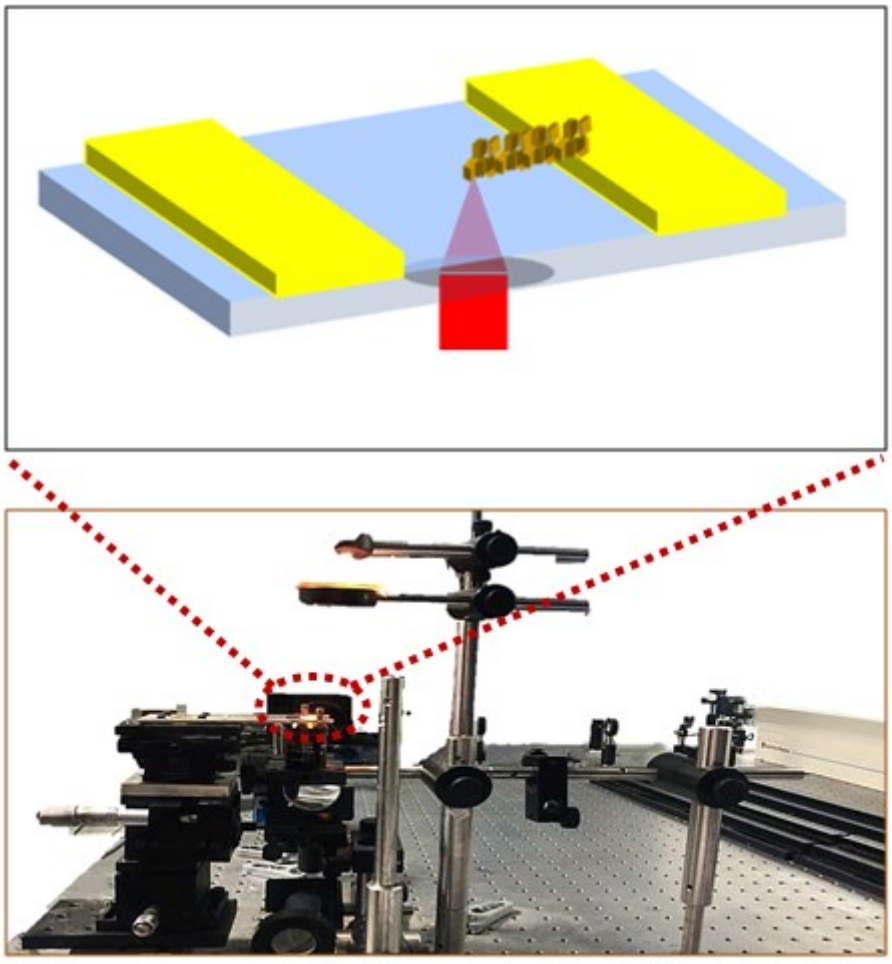

Fig. S1. The practicality photo of femtosecond laser processing system.

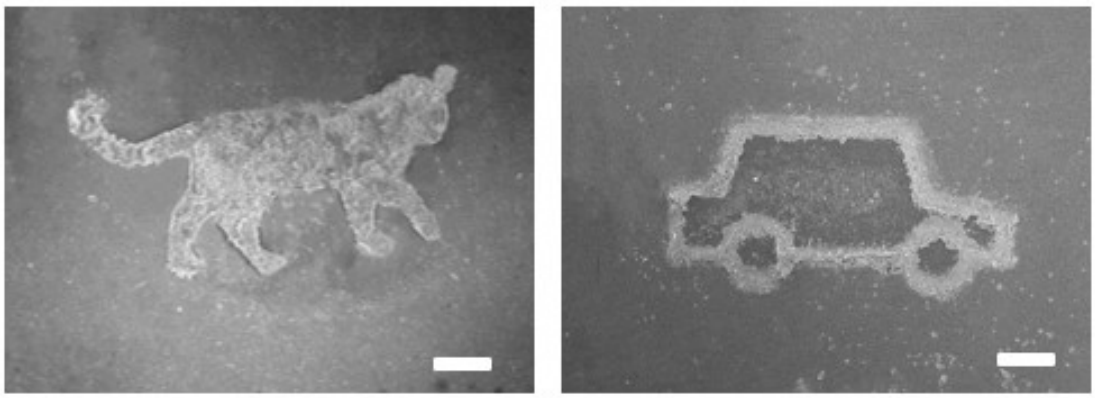

Fig. S2. SEM images of cartoon patterns cat and car made of Pd.

The scale bar is 10 μm.

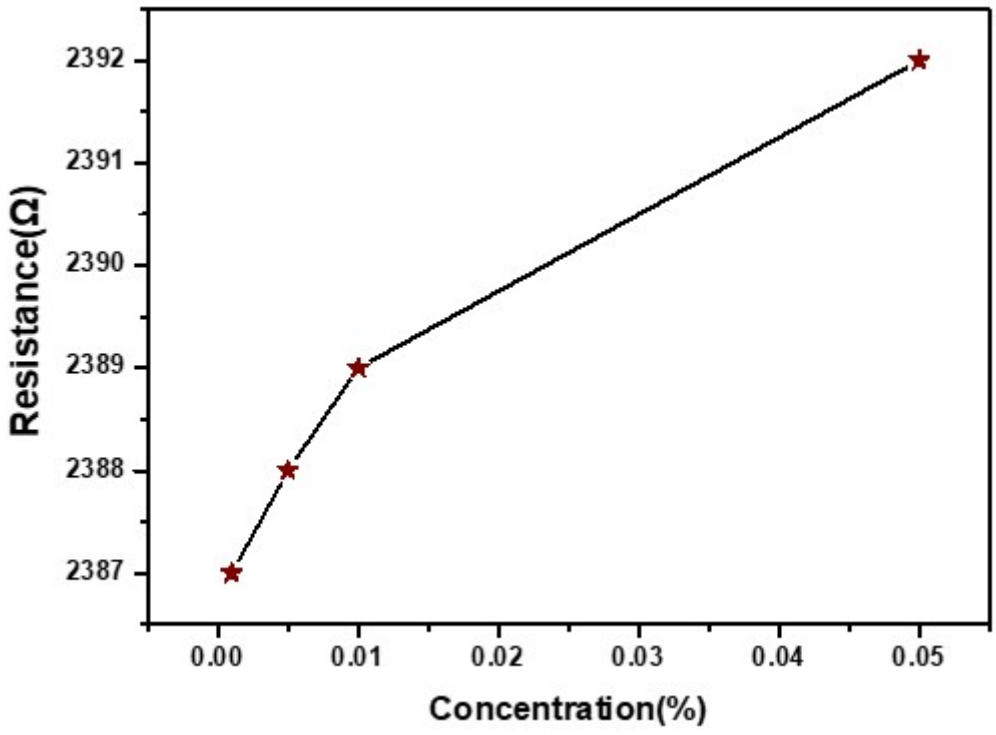

Fig. S3. The resistance changing curve of the Pd microwire exposes 0.001-0.05%

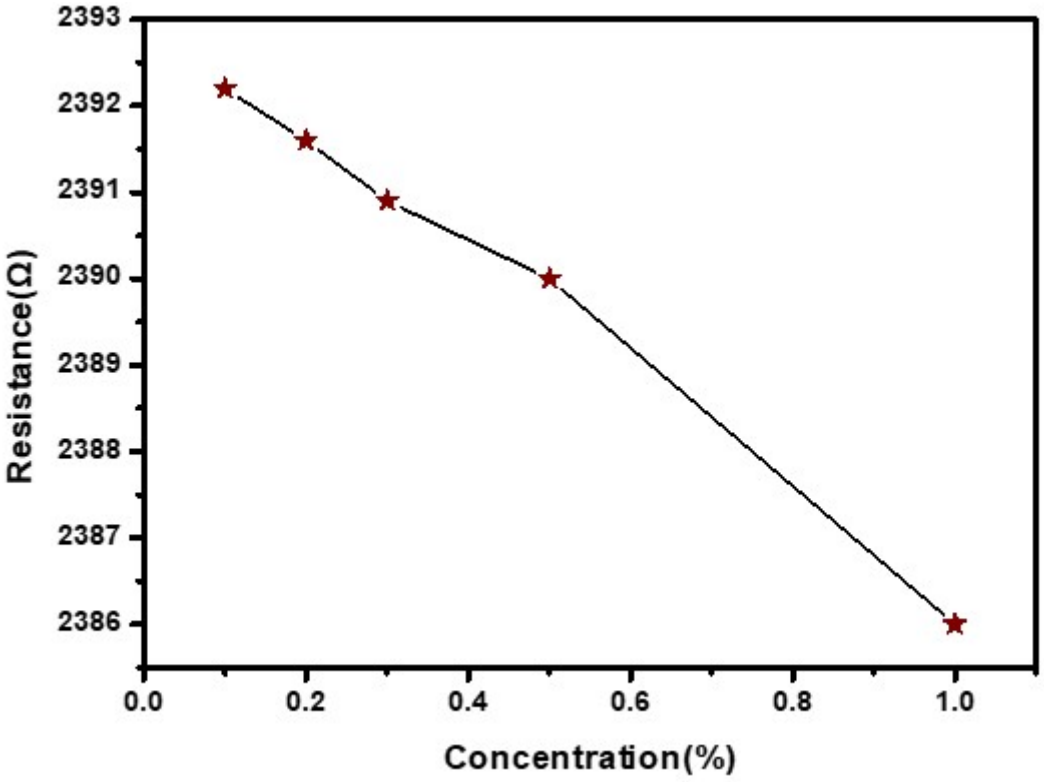

Fig. S4. The resistance changing curve of the Pd microwire exposes 0.01-0.1%

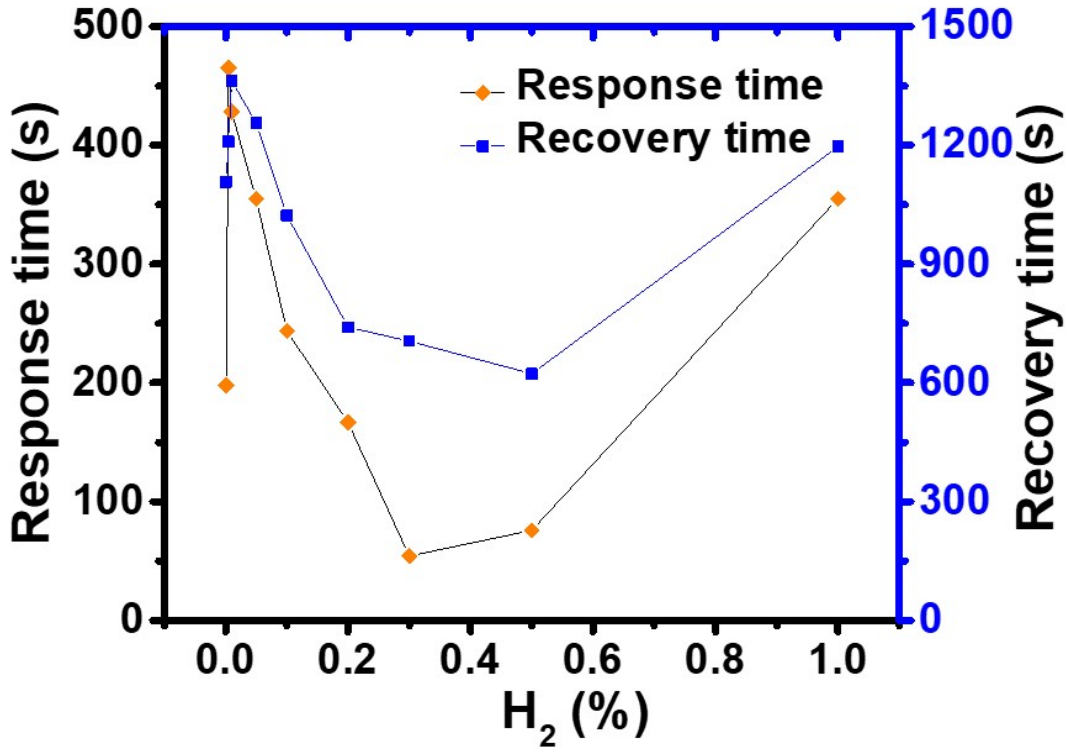

Fig. S5. Contrast between the response time and recovery time of Pd microwire sensor exposed to hydrogen concentration of 0.001% to 1.0% at room temperature.

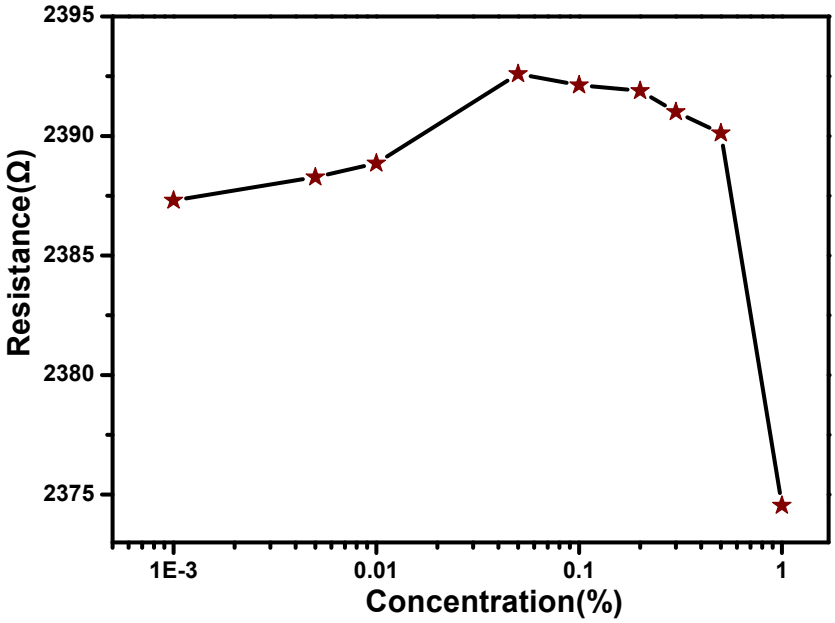

Fig. S6. The resistance changing of the Pd microwire exposed 0.01-1% after storing in ambience for two months.